HALOGEN

FREE



Vishay General Semiconductor

Surface Mount TRANSZORB® Transient Voltage Suppressors



PRIMARY CHARACTERISTICS					
V _{WM}	3.3 V				
P _{PPM}	100 W				
I _{FSM}	25 A				
T _J max.	150 °C				

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units specifically for protecting 3.3 V supplied sensitive equipment against transient overvoltages.

FEATURES

- Very low profile typical height of 0.65 mm
- · Ideal for automated placement
- Oxide planar chip junction
- Uni-directional polarity only
- Peak pulse power: 100 W (10/1000 μs)
- ESD capability: 15 kV (air), 8 kV (contact)
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: MicroSMP

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	P _{PPM} (1)(2)	100	W			
Peak pulse current with a 10/1000 µs waveform (fig. 1)	I _{PPM}	13.7	A			
Peak pulse current with a 8/20 μs waveform (fig. 1)	I _{PPM}	75	А			
Non repetitive peak forward surge current 8.3 ms single half sine-wave	I _{FSM} ⁽²⁾	25	Α			
Power dissipation T _L = 120 °C	P _D ⁽²⁾	1.0	W			
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C			

Notes

(1) Non-repetitive current pulse, per fig. 1

(2) Mounted on 6.0 mm x 6.0 mm copper pads to each terminal

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)											
DEVICE TYPE	DEVICE MARKING CODE	G VOLTAGE		I FAKAGE VOLTAGE AT V.		MAX. CLAMPING VOLTAGE AT V _C AT I _{PPM} (8/20 µs)		TYPICAL TEMPERATURE COEFFICIENT OF V _{BR}	TYP.JUNCTION CAPACITANCE C _J AT 0 V (1 MHZ)		
		٧	mA	μΑ	٧	V	Α	V	Α	(10 ⁻⁴ /°C)	pF
MSP3V3	KC	4.1	1.0	200	3.3	7.3	13.7	11.0	75	- 5.3	850

MSP3V3

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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal registeres	R _{0JA} (1)	125	°C/W			
Typical thermal resistance	R _{θJL} ⁽¹⁾	30	C/VV			

Note

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 mm x 6.0 mm copper pad areas. R_{BJL} is measured at the terminal of cathode band.

IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)							
STANDARD	TEST TYPE	SYMBOL	CLASS	VALUE			
AEC-Q101-001	Human body model (contact mode)	C = 100 pF, R = 1.5 kW	V	НЗВ	> 8 kV		
IEC 61000-4-2 (2)	Human body model (air discharge mode) (1)	C = 150 pF, R = 150 W	V _C	4	> 15 kV		

Notes

 $^{(1)}$ Immunity to IEC 61000-4-2 air discharge mode has a typical performance > 30 kV

⁽²⁾ System ESD standard

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
MSP3V3-M3/89A	0.006	89A	4500	7" diameter plastic tape and reel		
MSP3V3HM3/89A ⁽¹⁾	0.006	89A	4500	7" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

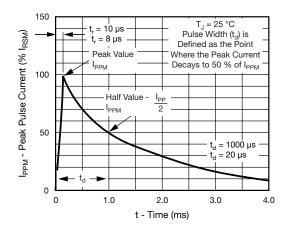


Fig. 1 - Pulse Waveform

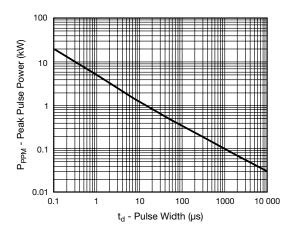


Fig. 2 - Peak Pulse Power Rating Curve



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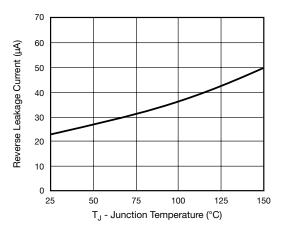


Fig. 3 - Relative Variation of Leakage Current vs. Junction Temperature

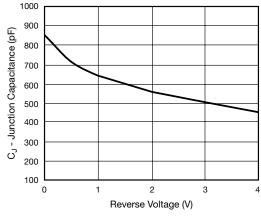


Fig. 5 - Typical Junction Capacitance

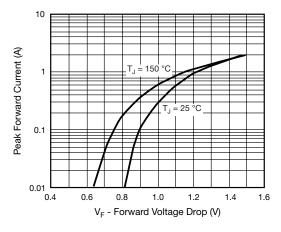


Fig. 4 - Typical Peak Forward Voltage Drop vs. Peak Forward Current

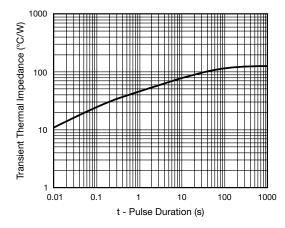
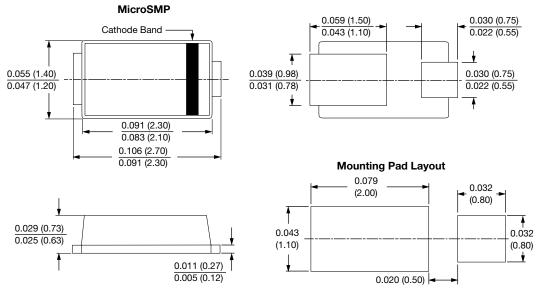


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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